Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7164	257/E21.277,758-760,762,763,751.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/04 15:28
L2	42	1 and ((carbon near silicon near oxide) SiOCH)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/04 15:44
L3	12	2 and ((silicon Si) near ("CH.sub.3" CH3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/04 15:45
L4	579	((carbon near silicon near oxide) SiOCH)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/04 15:44
L5	51	4 and ((silicon Si) near ("CH.sub.3" CH3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/04 15:45
L7	1	((insulat$3 dielectric) ADJ (layer$1 film$1)) AND carbon AND ((silicon Si) ADJ oxide) AND SiOCH AND (Si NEAR CH2) AND bond$3.CLM.	US-PGPUB; USPAT	OR	ON	2005/11/04 15:52